



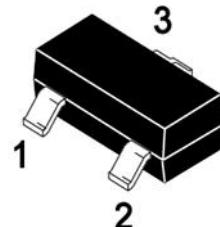
## SSCNA44GS6

High Frequency High Gain NPN Power BJT

### ➤ Features

VCB	VCE	VEB	IC
400V	400V	6V	200mA

### ➤ Pin configuration



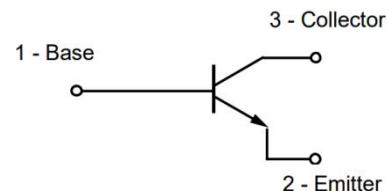
### ➤ Description

This device is designed for general-purpose high-voltage amplifiers and gas discharge display drivers. It is ideal for medium power amplification and switching.

SOT-23

### ➤ Applications

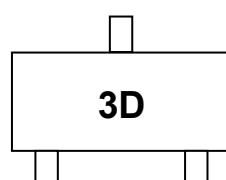
- Amplifying signal
- Electronic switch
- Oscillating circuit
- Variable resistance



Circuit Diagram

### ➤ Ordering Information

Device	Package	Shipping
SSCNA44GS6	SOT-23	3000/Reel



Marking (Top View)



➤ **Absolute Maximum Ratings( $T_A=25^\circ C$  unless otherwise noted)**

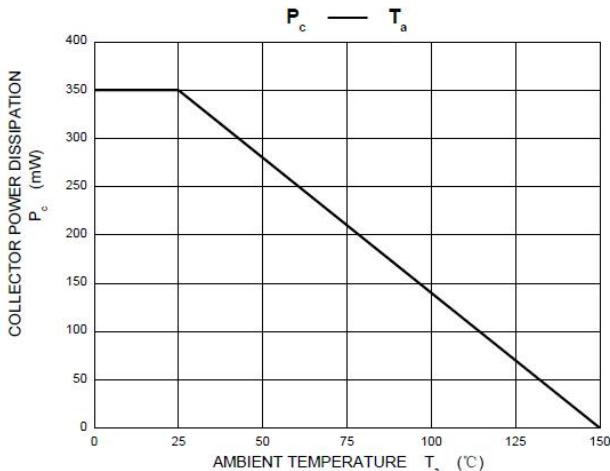
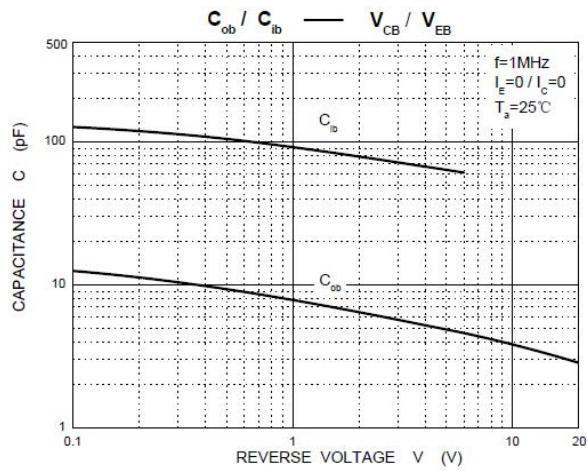
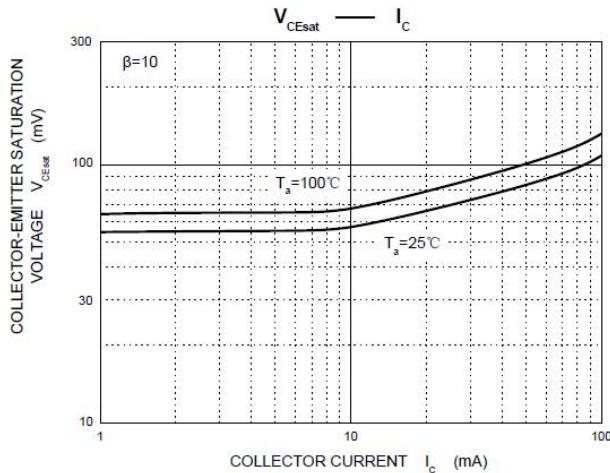
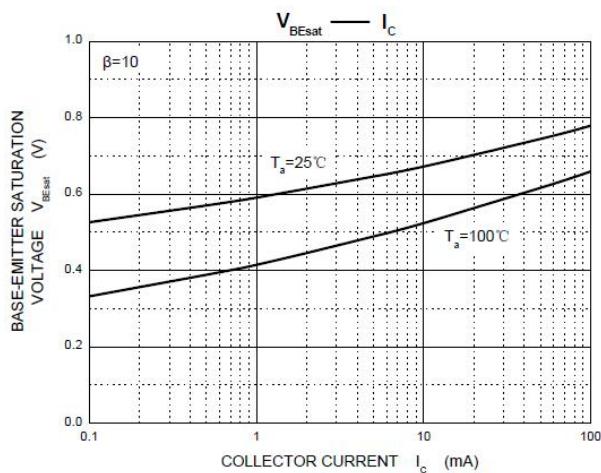
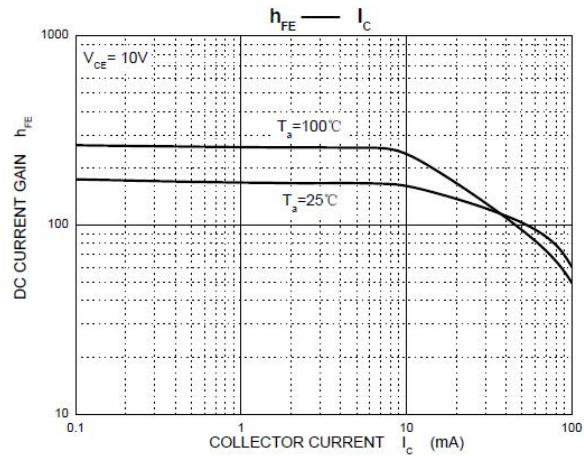
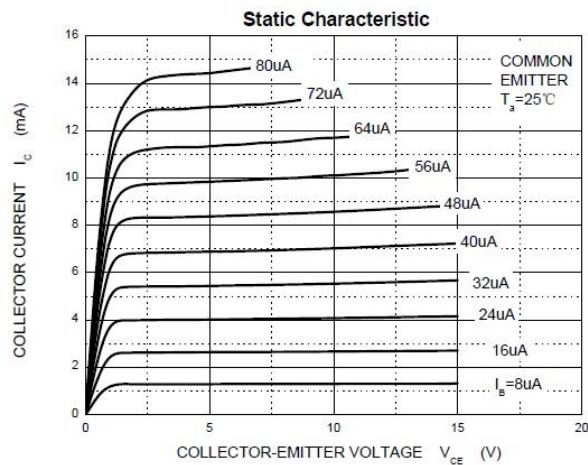
Parameter	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	400	V
Collector- Emitter Voltage	$V_{CEO}$	400	V
Emitter-Base Voltage	$V_{EBO}$	6	V
Collector Current-Continuous	$I_C$	200	mA
Collector Current-Peak	$I_{CM}$	300	mA
Collector Power Dissipation	$P_C$	350	mW
Thermal Resistance From Junction to Ambient	$R_{\theta JA}$	357	°C/W
Junction Temperature	$T_J$	-55 to 150	°C
Storage Temperature	$T_{STG}$	-55 to 150	°C

➤ **Electrical Characteristics ( $T_A=25^\circ C$  unless otherwise noted)**

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$BV_{CBO}$	$I_C=0.1mA, I_E=0$	400			V
Collector-emitter Breakdown Voltage	$BV_{CEO}$	$I_C=1mA, I_B=0$	400			V
Emitter -Base Breakdown Voltage	$BV_{EBO}$	$I_E=0.01mA, I_C=0$	6			V
Collector Cutoff Current	$I_{CBO}$	$V_{CB}=400V, I_E=0$			0.1	μA
Emitter Cutoff Current	$I_{EBO}$	$V_{EB}=4V, I_C=0$			0.1	μA
DC Current Gain	$h_{FE}^*$	$V_{CE}=10V, I_C=1mA$	40			
		$V_{CE}=10V, I_C=10mA$	50		200	
		$V_{CE}=10V, I_C=50mA$	45			
		$V_{CE}=10V, I_C=100mA$	40			
Collector-Emitter Saturation Voltage	$V_{CE(sat)1}^*$	$I_C=1mA, I_B=0.1mA$			0.4	V
	$V_{CE(sat)2}^*$	$I_C=10mA, I_B=1mA$			0.5	V
	$V_{CE(sat)3}^*$	$I_C=50mA, I_B=5mA$			0.75	V
Base-Emitter Saturation Voltage	$V_{BE(sat)}^*$	$I_C=10mA, I_B=1mA$			0.75	V
Collector Output Capacitance	$C_{ob}$	$V_{CB}=20V, I_E=0, f=1MHz$			7	pF
Emitter Input Capacitance	$C_{ib}$	$V_{EB}=0.5V, I_C=0, f=1MHz$			130	pF
Transition frequency	$f_T$	$V_{CE}=20V, I_C=10mA$ $f=30MHz$	50			MHz

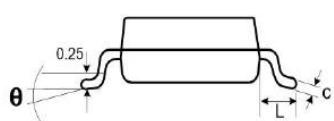
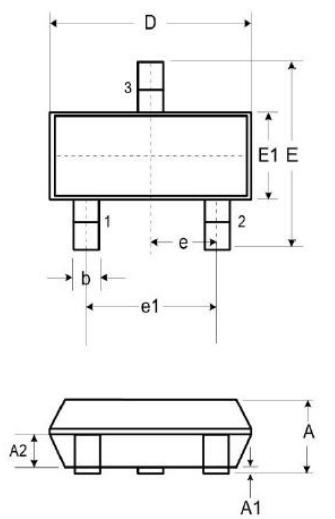
\*Pulse test: pulse width  $\leq 300\mu s$ , duty cycle  $\leq 2.0\%$ .

➤ Typical Performance Characteristics ( $T_a=25^\circ\text{C}$  unless otherwise noted)



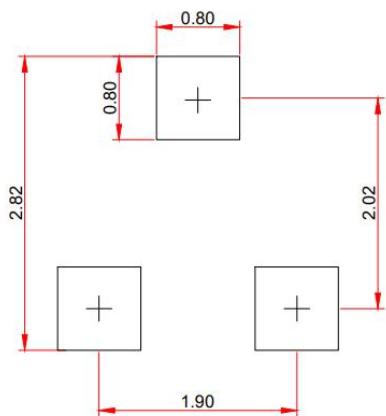
➤ **Package Information**

● **Mechanical Data**



DIM	Millimeters		
	Min.	Typ.	Max.
<b>A</b>	0.89	-	1.12
<b>A1</b>	0.01	-	0.10
<b>A2</b>	0.88	0.95	1.02
<b>b</b>	0.30	-	0.51
<b>c</b>	0.08	-	0.18
<b>D</b>	2.80	2.90	3.04
<b>E</b>	2.10	2.37	2.64
<b>E1</b>	1.20	1.30	1.40
<b>e1</b>		1.90	
<b>e</b>		0.95	
<b>L</b>	0.40	0.50	0.60
<b>L1</b>		0.55	
<b>N</b>		3	
<b>θ</b>	0°	-	8°

● **Recommended Pad outline (Unit: mm)**



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